

Single Phase Bridge (Power Modules), 25/35 A


GBPC...A

GBPC...W

FEATURES

- Universal, 3 way terminals: push-on, wrap around or solder
- High thermal conductivity package, electrically insulated case
- Positive polarity symbol molded on the plastic case
- Center hole fixing
- Glass passivated diode chips
- Excellent power/volume ratio
- Nickel plated terminals solderable using lead (Pb)-free solder; Solder Alloy Sn/Ag/Cu (SAC305); Solder temperature 260 to 275 °C
- Wire lead version available
- UL E300359 approved 
- RoHS compliant
- Designed and qualified for industrial and consumer level


RoHS
COMPLIANT

PRODUCT SUMMARY

I_o	25/35 A
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DESCRIPTION/APPLICATIONS

A range of extremely compact, encapsulated single phase bridge rectifiers offering efficient and reliable operation. They are intended for use in general purpose and instrumentation applications

MAJOR RATINGS AND CHARACTERISTICS

SYMBOL	CHARACTERISTICS	GBPC25	GBPC35	UNITS
I_o		25	35	A
	T_c	60	55	°C
I_{FSM}	50 Hz	400	475	A
	60 Hz	420	500	
I^2t	50 Hz	790	1130	A ² s
	60 Hz	725	1030	
V_{RRM}	Range	200 to 1200		V
T_J		- 55 to 150		°C

ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS					
TYPE NUMBER	VOLTAGE CODE	V_{RRM} , MAXIMUM REPETITIVE PEAK AC REVERSE VOLTAGE $T_J = T_J$ MAXIMUM V	V_{RSM} , MAXIMUM NON-REPETITIVE PEAK AC REVERSE VOLTAGE $T_J = T_J$ MAXIMUM V	I_{RRM} MAXIMUM AT RATED V_{RRM} $T_J = T_J$ MAXIMUM mA	I_{RRM} MAXIMUM DC REVERSE CURRENT AT $T_J = 125^\circ\text{C}$ μA
GBPC25/35..A ⁽¹⁾ GBPC25/35..W	02	200	275	2	500
	04	400	500		
	06	600	725		
	08	800	900		
	10	1000	1100		
	12	1200	1300		

Note

(1) See Ordering Information table at the end of datasheet

FORWARD CONDUCTION								
PARAMETER	SYMBOL	TEST CONDITIONS			GBPC25	GBPC35	UNITS	
Maximum DC output current at case temperature	I _O	Resistive or inductive load			25	35	A	
		Capacitive load			20	28		
					60	55	°C	
Maximum peak, one-cycle non-repetitive forward current	I _{FSM}	t = 10 ms	No voltage reapplied	Initial T _J = T _J maximum	400	475	A	
		t = 8.3 ms			420	500		
		t = 10 ms	100 % V _{RRM} reapplied		335	400		
		t = 8.3 ms			350	420		
Maximum I ² t for fusing	I ² t	t = 10 ms	No voltage reapplied		790	1130	A ² s	
		t = 8.3 ms			725	1030		
		t = 10 ms	100 % V _{RRM} reapplied		560	800		
		t = 8.3 ms			512	730		
Maximum I ² √t for fusing	I ² √t	I ² t for time t _x = I ² √t × √t _x ; 0.1 ≤ t _x ≤ 10 ms, V _{RRM} = 0 V			7.9	11.3	kA ² √s	
Low level of threshold voltage	V _{F(TO)1}	(16.7 % × π × I _{F(AV)}) < I < π × I _{F(AV)} , T _J maximum			0.76	0.77	V	
High level of threshold voltage	V _{F(TO)2}	(I > π × I _{F(AV)}), T _J maximum			0.89	0.92		
Low level forward slope resistance	r _{t1}	(16.7 % × π × I _{F(AV)}) < I < π × I _{F(AV)} , T _J maximum			8.2	4.852	mΩ	
High level forward slope resistance	r _{t2}	(I > π × I _{F(AV)}), T _J maximum			6.8	3.867		
Maximum forward voltage drop	V _{FM}	T _J = 25 °C, I _{FM} = I _{Favg} (arm)			1.1		V	
Maximum DC reverse current	I _{RRM}	T _J = 25 °C, per diode at V _{RRM}			5.0		μA	
RMS isolation voltage base plate	V _{INS}	f = 50 Hz, t = 1 s			2700		V	



THERMAL AND MECHANICAL SPECIFICATIONS

PARAMETER	SYMBOL	TEST CONDITIONS	GBPC25	GBPC35	UNITS
Junction and storage temperature range	T _J , T _{Stg}		- 55 to 150		°C
Maximum thermal resistance, junction to case per bridge	R _{thJC}	DC operation	1.7	1.4	K/W
Maximum thermal resistance, case to heatsink	R _{thCS}	Mounting surface, smooth, flat and greased	0.2		
Approximate weight			16		g
Mounting torque ± 10 %		Bridge to heatsink	2.0		N · m (lbf · in)

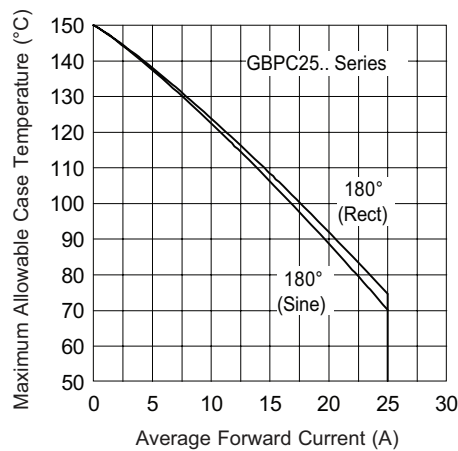


Fig. 1 - Current Ratings Characteristics

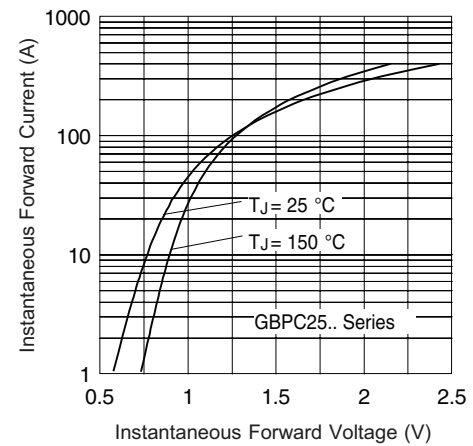


Fig. 2 - Forward Voltage Drop Characteristics

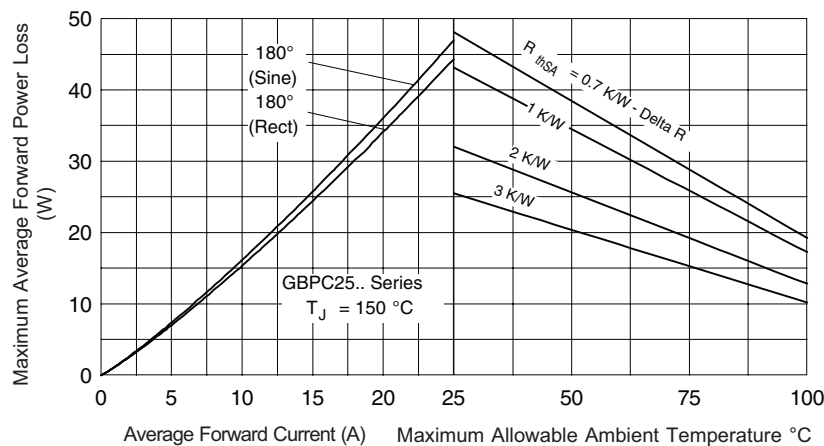
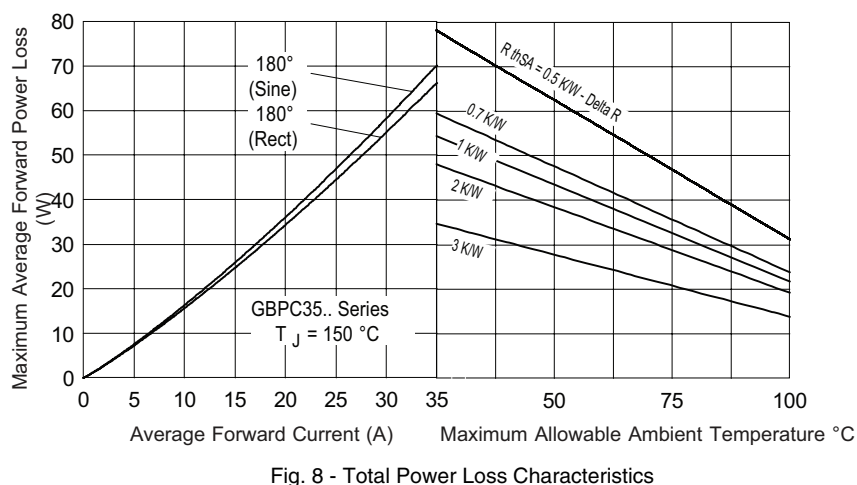
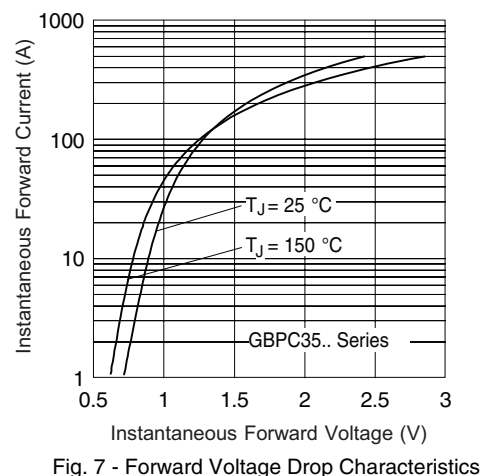
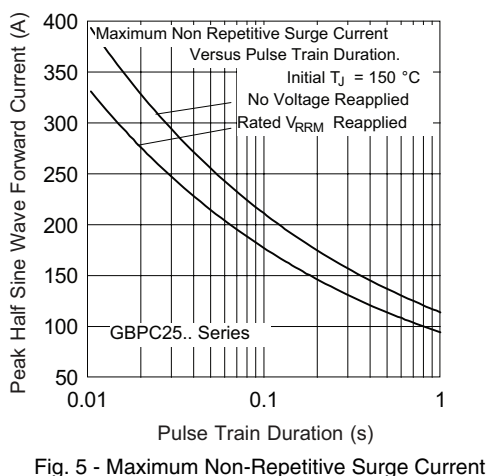
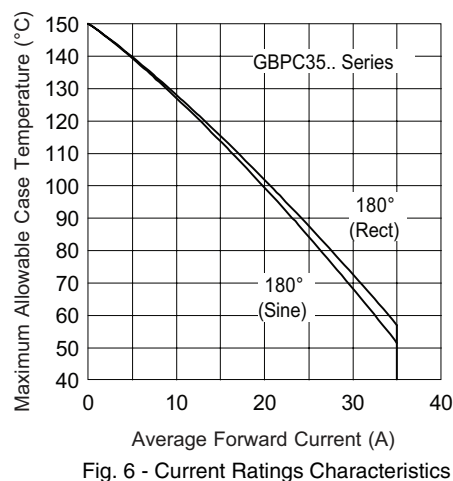
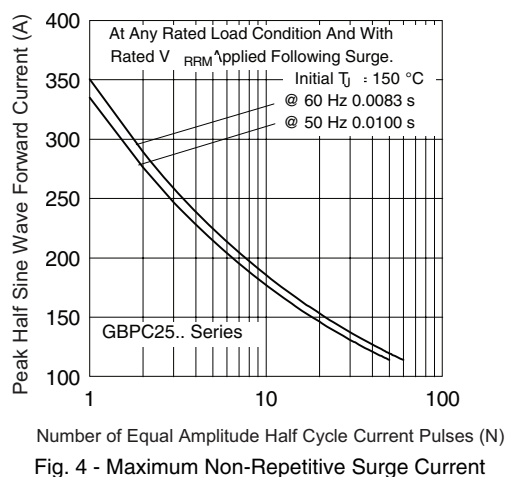


Fig. 3 - Total Power Loss Characteristics



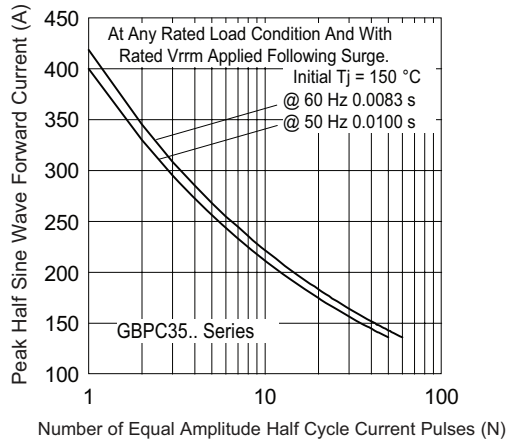


Fig. 9 - Maximum Non-Repetitive Surge Current

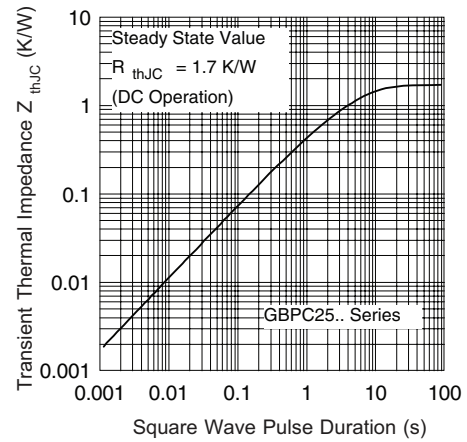


Fig. 11 - Thermal Impedance Z_{thJC} Characteristic

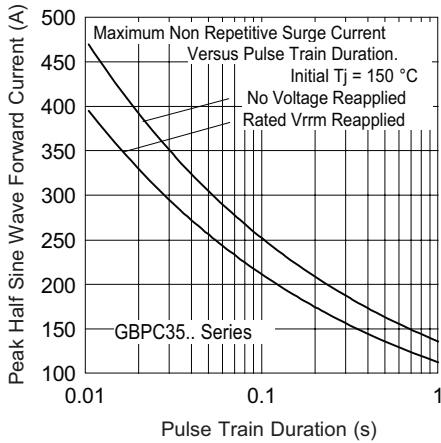


Fig. 10 - Maximum Non-Repetitive Surge Current

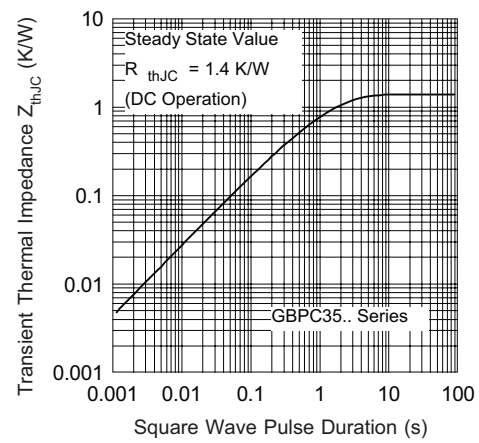


Fig. 12 - Thermal Impedance Z_{thJC} Characteristic

ORDERING INFORMATION TABLE

Device code

GBPC	35	12	A
1	2	3	4

1 - Circuit configuration:
Single phase bridge coding

2 - Current rating code

3 - Voltage code $\times 100 = V_{RRM}$

4 - Diode bridge rectifier:

- A = Standard fast-on terminal
- W = Wire lead

25 = 25 A (average)
35 = 35 A (average)

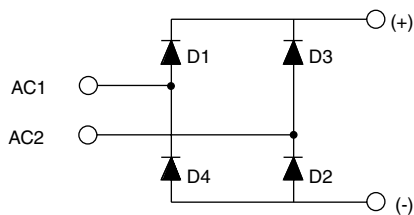
GBPC.. Series

Vishay High Power Products

Single Phase Bridge
(Power Modules), 25/35 A



CIRCUIT CONFIGURATION



LINKS TO RELATED DOCUMENTS

Dimensions

<http://www.vishay.com/doc?95331>



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